TOSHIBA CMOS Linear Integrated Circuit Silicon Monolithic

TCR3LM series

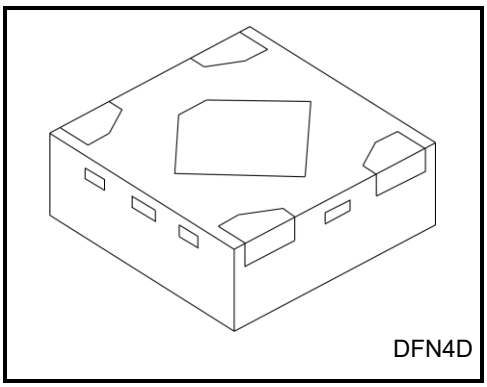
Low quiescent current, 300 mA CMOS Low Dropout Regulator in ultra small package

1. Description

The TCR3LM series are CMOS general-purpose single-output voltage regulators with an on/off control input, featuring low quiescent current.

These voltage regulators are available in fixed output voltages between 0.8 V and 5.0 V and capable of driving up to 300 mA. They feature Overcurrent protection, Thermal shutdown and Auto-discharge.

The TCR3LM series is offered in the ultra small plastic mold package DFN4D (1.0 mm x 1.0 mm; t 0.37 mm (typ.)) and has low quiescent current (I_B = 1.2 µA (typ.) at I_{OUT} = 0 mA). As small ceramic input and output capacitors 0.47 µF can be used with the TCR3LM series, these devices are ideal for portable applications that require high-density board assembly such as cellular phones.



Weight: 1.1 mg (typ.)

2. Applications

Power IC developed for portable applications

3. Features

- Ultra small package DFN4D (1.0 mm x 1.0 mm; t 0.37 mm (typ.)).
- Low quiescent current ($I_{B(ON)}$ = 1.2 µA (typ.) at I_{OUT} = 0 mA)
- High Ripple rejection ratio (74 dB (typ.) at 100 Hz, 0.8 V-output)
- Fast load transient response (-70/+35 mV at 2.8 V-output, I_{OUT} = 1 mA ⇔ 100 mA)
- Low Dropout voltage (V_{DO} = 213 mV (typ.) at 2.8 V-output, I_{OUT} = 200 mA)
- Wide range output voltage line up (V_{OUT} = 0.8 to 5.0 V)
- Overcurrent protection
- Thermal shutdown
- Auto-discharge
- Inrush current protection circuit
- Pull down connection between CONTROL and GND
- Ceramic capacitors can be used (C_{IN} = 0.47 µF, C_{OUT} = 0.47 µF)

Start of commercial production
2023-03

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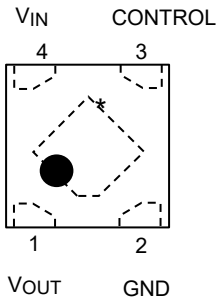
4. Absolute Maximum Ratings (Note) (Ta = 25 °C)

Characteristics	Symbol	Rating	Unit
Input voltage	V_{IN}	-0.3 to 6.0	V
Control voltage	V_{CT}	-0.3 to V_{IN} + 0.3 ≤ 6.0	V
Output voltage	V_{OUT}	-0.3 to V_{IN} + 0.3 ≤ 6.0	V
Power dissipation	P_D	420 (Note 1)	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	−55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Rating at mounting on a board
Glass epoxy(FR4) board dimension: 40 mm x 40 mm x 1.6 mm, both sides of board.
Metal pattern ratio: a surface approximately 50 %, the reverse side approximately 50 %
Through hole: diameter 0.5 mm x 24 pcs

5. Pin Assignment (top view)



*Center electrode should be connected to GND or Open

6. Operating Ranges

Characteristics	Symbol	Rating		Unit
Input voltage	V_{IN}	1.4 to 5.5 (Note 2)		V
Control voltage	V_{CT}	0 to V_{IN}		V
Output voltage	V_{OUT}	0.8 to 5.0		V
Output current	I_{OUT}	DC	300	mA
Operation Temperature	T_{opr}	-40 to 85		°C
Output Capacitance	C_{OUT}	≥ 0.47		µF
Input Capacitance	C_{IN}	≥ 0.47		µF

Note 2: Please refer to Dropout Voltage Characteristics and use it within Absolute Maximum Ratings Junction temperature and Operation Temperature Ranges.

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7. List of Products Number, Output voltage and Marking

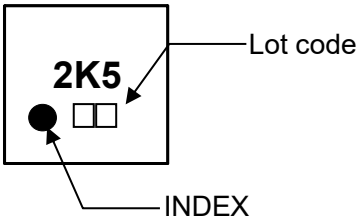
Product No.	Output voltage (V)	Marking
TCR3LM08A	0.8	0K8
TCR3LM085A	0.85	0KC
TCR3LM09A	0.9	0K9
TCR3LM095A	0.95	0KD
TCR3LM10A	1.0	1K0
TCR3LM105A	1.05	1KE
TCR3LM11A	1.1	1K1
TCR3LM115A	1.15	1KF
TCR3LM12A	1.2	1K2
TCR3LM13A	1.3	1K3
TCR3LM15A	1.5	1K5
TCR3LM16A	1.6	1K6
TCR3LM17A	1.7	1K7
TCR3LM18A	1.8	1K8
TCR3LM185A	1.85	1KH
TCR3LM19A	1.9	1K9
TCR3LM195A	1.95	1KK
TCR3LM20A	2.0	2K0
TCR3LM22A	2.2	2K2
TCR3LM25A	2.5	2K5
TCR3LM26A	2.6	2K6
TCR3LM27A	2.7	2K7
TCR3LM28A	2.8	2K8
TCR3LM285A	2.85	2KJ
TCR3LM29A	2.9	2K9
TCR3LM30A	3.0	3K0
TCR3LM31A	3.1	3K1
TCR3LM32A	3.2	3K2
TCR3LM33A	3.3	3K3
TCR3LM35A	3.5	3K5
TCR3LM36A	3.6	3K6
TCR3LM40A	4.0	4K0
TCR3LM41A	4.1	4K1
TCR3LM42A	4.2	4K2
TCR3LM45A	4.5	4K5
TCR3LM48A	4.8	4K8
TCR3LM50A	5.0	5K0

Please ask your local retailer about the devices with other output voltages.

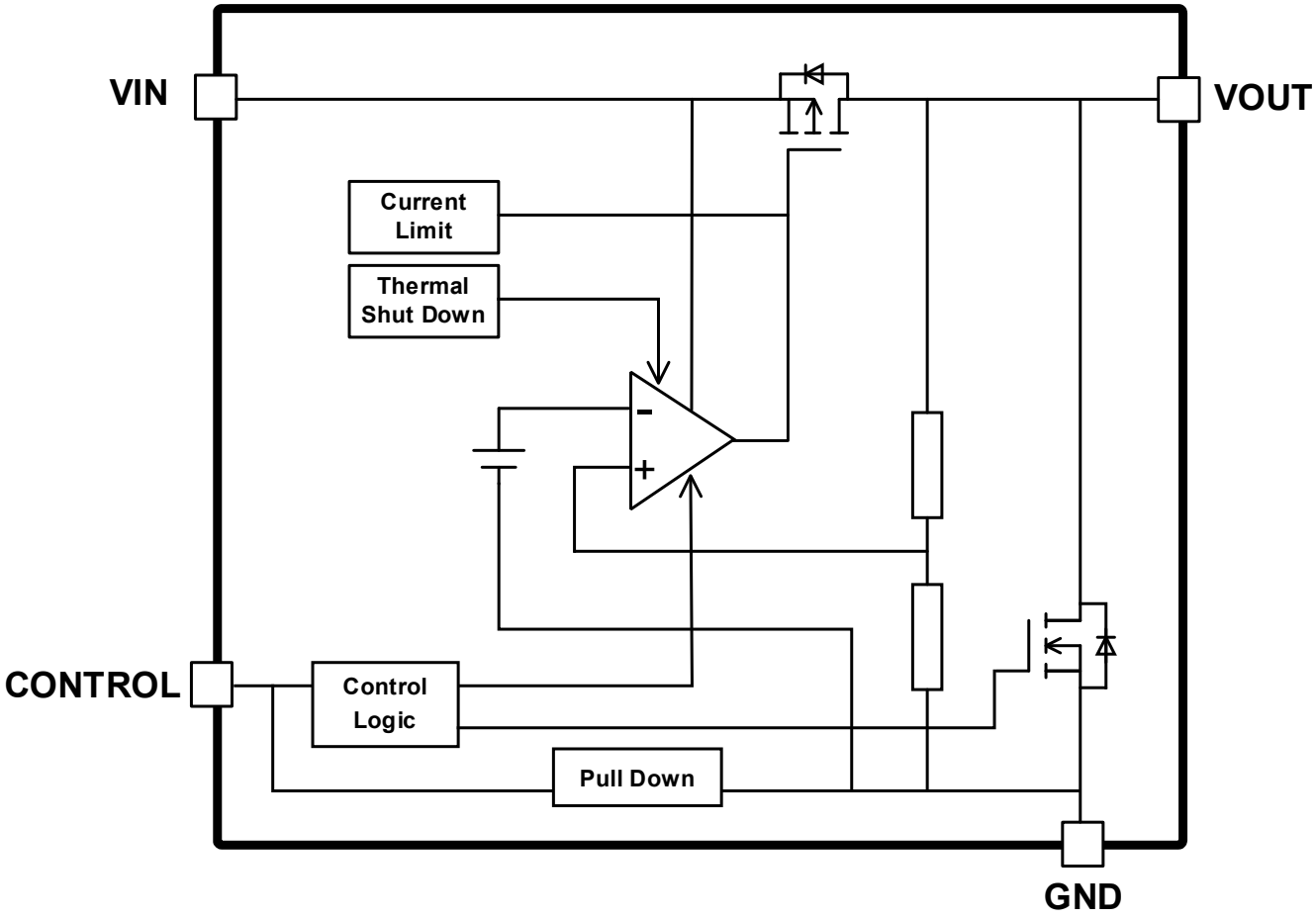
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8. Top Marking (top view)

Example: TCR3LM25A (2.5 V output)



9. Block Diagram



10. Electrical Characteristics

(Unless otherwise specified, V_{IN} = 2.5 V or V_{OUT} + 1.0 V (whichever is greater), V_{IN} = 5.5 V (V_{OUT} = 5.0 V), C_{IN} = C_{OUT} = 0.47 µF)

Characteristics	Symbol	Test Condition		T_j = 25 °C			T_j = -40 to 85 °C (Note 8)		Unit
				Min	Typ.	Max	Min	Max	
Output voltage accuracy	V_{OUT}	I_{OUT} = 50 mA V_{IN} = V_{OUT} + 1 V (Note 3)	V_{OUT} < 1.8 V	-18	—	+18	—	—	mV
			1.8 V ≤ V_{OUT}	-1	—	+1	—	—	%
Line regulation	Reg·line	V_{OUT} + 1 V ≤ V_{IN} ≤ 5.5 V I_{OUT} = 1 mA		—	5	—	—	12	mV
Load regulation	Reg·load	1 mA ≤ I_{OUT} ≤ 200 mA (Note 4)		—	13	—	—	28	mV
Quiescent current	$I_{B(ON)}$	I_{OUT} = 0 mA, V_{IN} = 5.5 V (Note 6)		—	1.2	—	—	2.2	µA
Stand-by current	$I_{B\ (OFF)}$	V_{CT} = 0 V, V_{IN} = 5.5 V (Note 6)		—	0.1	—	—	0.2	µA
Control pull down current	I_{CT}	—		—	0.1	—	—	0.2	µA
Drop-out voltage (Note 9)	V_{DO}	I_{OUT} = 200 mA	V_{OUT} = 1.8 V	—	344	—	—	445	mV
			V_{OUT} = 2.8 V	—	213	—	—	290	mV
			V_{OUT} = 3.3 V	—	177	—	—	251	mV
			V_{OUT} = 5.0 V	—	137	—	—	205	mV
Output noise voltage	V_{NO}	V_{IN} = V_{OUT} + 1 V I_{OUT} = 10 mA 10 Hz ≤ f ≤ 100 kHz, Ta = 25 °C (Note 4)		—	53	—	—	—	μV_{rms}
Ripple rejection ratio	R.R.	V_{IN} = V_{OUT} + 1 V I_{OUT} = 10 mA, V_{Ripple} = 200 mV_{p-p}, Ta = 25 °C (Note 4)	f = 100 Hz	—	74	—	—	—	dB
			f = 1 kHz	—	66	—	—	—	
			f = 10 kHz	—	50	—	—	—	
			f = 100 kHz	—	43	—	—	—	
Load transient response	$\varDelta V_{OUT}$	I_{OUT} = 1 mA → 100 mA (Note 5)		—	-70	—	—	—	mV
		I_{OUT} = 100 mA → 1 mA (Note 5)		—	+35	—	—	—	
Output current limit	I_{CL}	V_{OUT} = $V_{OUT(NOM)}$*90 % (Note 7)		—	—	—	300	450	mA
Thermal shutdown threshold	T_{SDH}	T_J rising		—	160	—	—	—	°C
	T_{SDL}	T_J falling		—	140	—	—	—	°C
Control voltage (HIGH)	V_{CTH}	Control pin input voltage “HIGH”		—	—	—	0.9	5.0	V
Control voltage (LOW)	V_{CTL}	Control pin input voltage “LOW”		—	—	—	—	0.4	V
Discharge on resistance	R_{SD}	(Note 5)		—	25	—	—	—	Ω

Note 3: stable state with fixed I_{OUT} condition
Note 4: V_{OUT} = 0.8 V
Note 5: V_{OUT} = 2.8 V
Note 6: except Control pull down current (I_{CT})
Note 7: Pulse measurement
Note 8: This parameter is warranted by design.
Note 9: V_{DO} = V_{IN1} - (V_{OUT1} x 0.97)
V_{OUT1} is the output voltage when V_{IN} = V_{OUT} + 1.0 V.
V_{IN1} is the input voltage at which the output voltage becomes 97 % of V_{OUT1} after gradually decreasing the input voltage.

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11. Dropout voltage table

(C_{IN} = 0.47 µF, C_{OUT} = 0.47 µF)

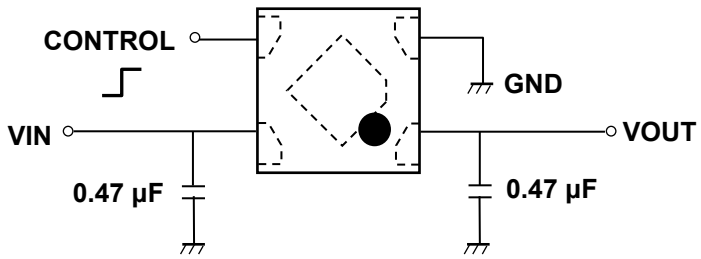
Output voltages	I_{OUT} = 200 mA			Unit
	Min	Typ.	Max (Note 10)	
0.8 V ≤ V_{OUT} < 1.5 V	—	(Note 11)	(Note 11)	mV
1.5 V	—	500 (Note 11)	615 (Note 11)	mV
1.6 V	—	441	550	mV
1.7 V	—	382	485	mV
1.8 V, 1.85 V	—	344	445	mV
1.9 V, 1.95 V	—	331	425	mV
2.0 V	—	318	410	mV
2.2 V	—	291	375	mV
2.5 V	—	252	325	mV
2.6 V	—	239	310	mV
2.7 V	—	226	300	mV
2.8 V, 2.85 V	—	213	290	mV
2.9 V	—	202	282	mV
3.0 V, 3.1 V	—	192	274	mV
3.2 V	—	182	259	mV
3.3 V	—	177	251	mV
3.5 V, 3.6 V	—	173	244	mV
4.0 V	—	161	237	mV
4.1 V		158	234	mV
4.2 V	—	156	230	mV
4.5 V	—	149	221	mV
4.8 V	—	142	211	mV
5.0 V	—	137	205	mV

Note 10: T_j = -40 to 85 °C. This parameter is guaranteed by design
Note 11: Operating Voltage of V_{IN} should be over 2.5 V.

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12. Application Note

12.1. Recommended Application Circuit



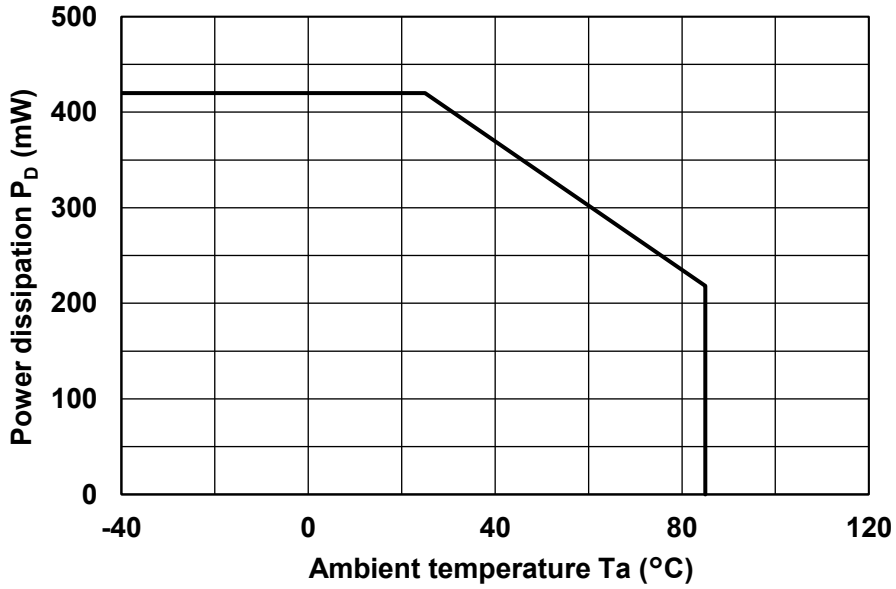
CONTROL voltage	Output voltage
HIGH	ON
LOW	OFF
OPEN	OFF

The figure above shows the recommended configuration for using a Low-Dropout regulator. Insert a capacitor at V_{OUT} and V_{IN} pins for stable input/output operation. (Ceramic capacitors can be used).

12.2. Power Dissipation

Board-mounted power dissipation ratings for TCR3LM series are available in the Absolute Maximum Ratings table. Power dissipation is measured on the board condition shown below.

[The Board Condition]
Board material: Glass epoxy (FR4)
Board dimension: 40 mm x 40 mm (both sides of board), t= 1.6 mm
Metal pattern ratio: a surface approximately 50 %, the reverse side approximately 50 %
Through hole: diameter 0.5 mm x 24 pcs



12.3. Attention in Use

- Output Capacitors
  Ceramic capacitors can be used for these devices. However, because of the type of the capacitors, there might be unexpected thermal features. Please consider application condition for selecting capacitors. And Toshiba recommend ceramic capacitor.

- TCR3LM series has Bias current; $I_{B(ON)}$ characteristic that controlled depending on I_{OUT}.
  When the output current required is very low, TCR3LM series operates with low $I_{B(ON)}$. In this state, load transient response characteristic are inferior than normal characteristics.
  Regarding output current that switches $I_{B(ON)}$ state, TCR3LM series has hysteresis to control. When output current is increased, good load transient response characteristics are provided with $I_{B(ON)}$ becoming high. In the case of decreasing the I_{OUT}, TCR3LM series keeps good characteristics until the $I_{B(ON)}$ switches to a low state.

- Mounting
  The long distance between IC and output capacitor might affect phase assurance by impedance in wire and inductor. For stable power supply, output capacitor need to mount near IC as much as possible. Also VIN and GND pattern need to be large and make the wire impedance small as possible.

- Permissible Loss
  Please have enough design patterns for expected maximum permissible loss. And under consideration of surrounding temperature, input voltage, and output current etc., we recommend proper dissipation ratings for maximum permissible loss; in general maximum dissipation rating is 70 to 80 %.

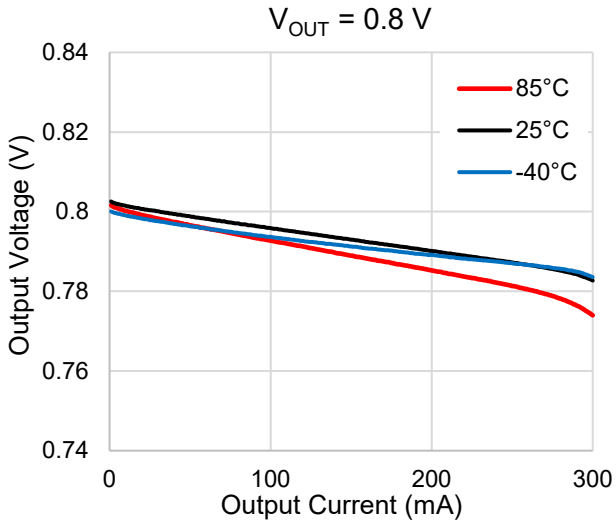
- Over current Protection and Thermal shut down function
  Over current protection and Thermal shut down function are designed in these products, but these are not designed to constantly ensure the suppression of the device within operation limits. Depending on the condition during actual usage, it could affect the electrical characteristic specification and reliability. Also note that if output pins and GND pins are not completely shorted out, these products might be break down. When using these products, please read through and understand the concept of dissipation for absolute maximum ratings from the above mention or our ‘Semiconductor Reliability Handbook’. Then use these products under absolute maximum ratings in any condition. Furthermore, Toshiba recommend inserting failsafe system into the design.

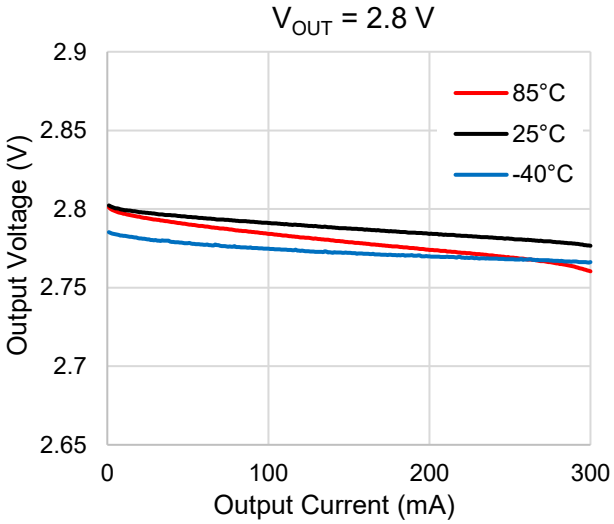
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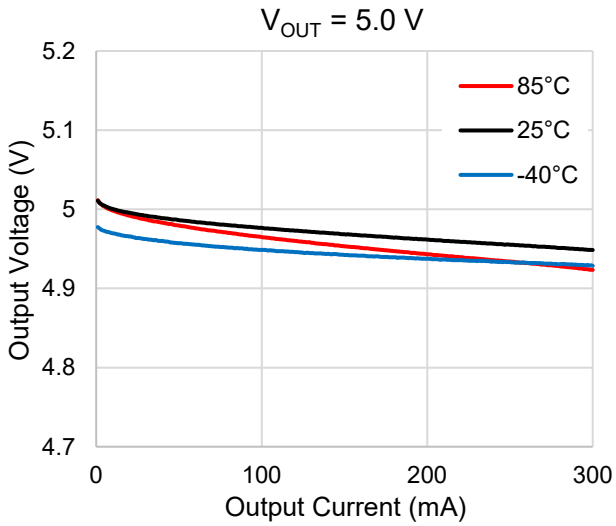
13. Representation Typical Characteristics (Note)

13.1. Output Voltage vs. Output Current

(V_{IN} = 2.5 V (V_{OUT} = 0.8 V) or 3.8 V (V_{OUT} = 2.8 V) or 5.5 V (V_{OUT} = 5.0 V))



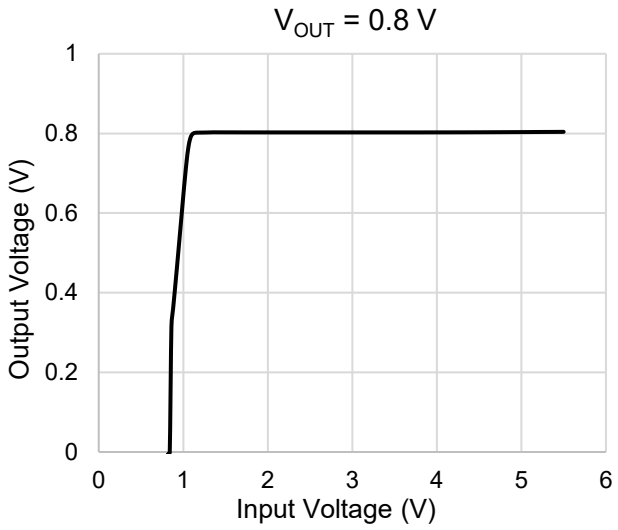


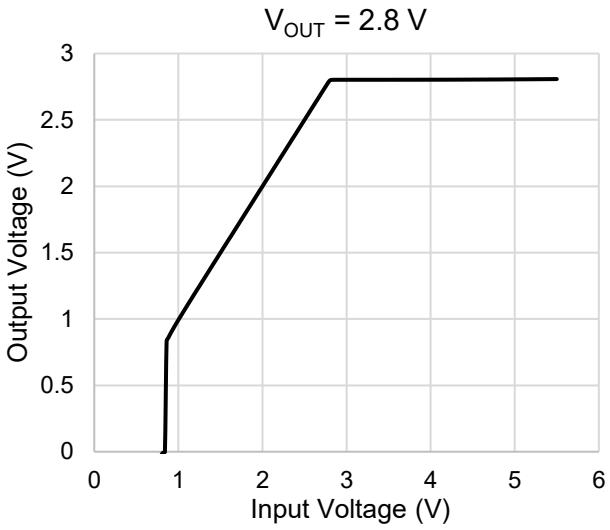


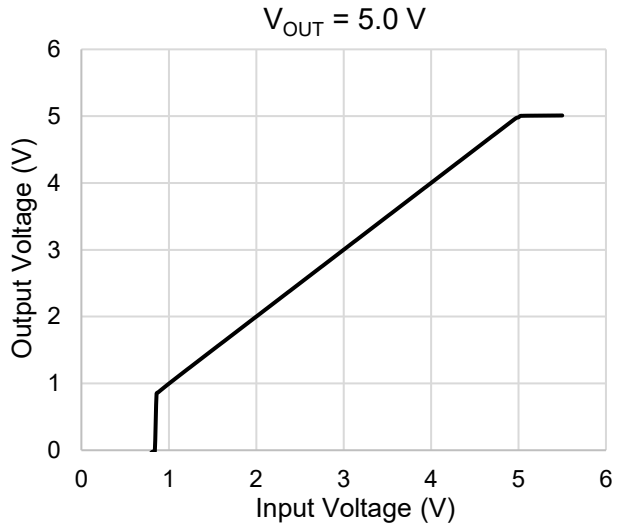
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

13.2. Output Voltage vs. Input Voltage

(I_{OUT} = 1 mA, Ta = 25 °C)



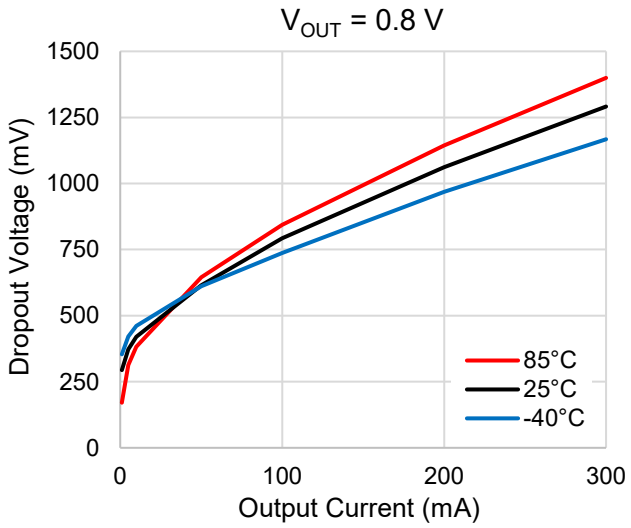


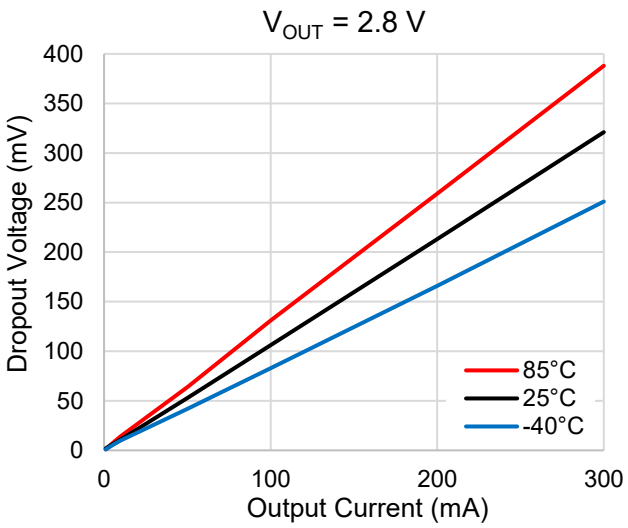


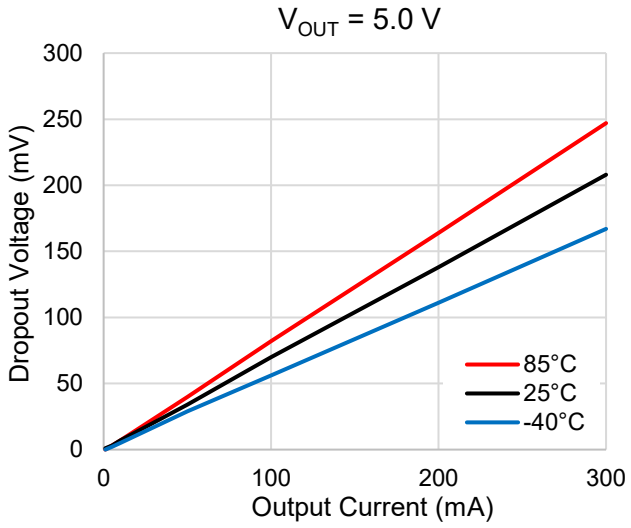
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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13.3. Dropout Voltage vs. Output Current





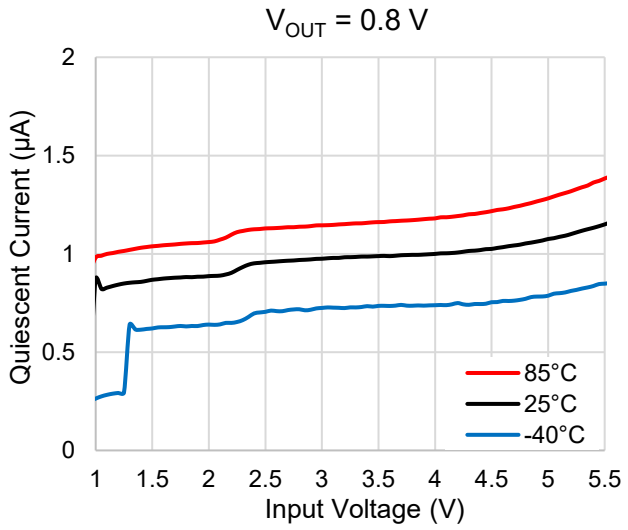


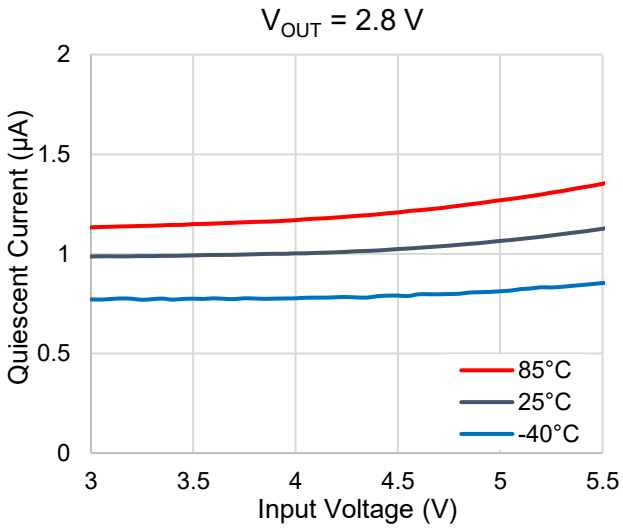
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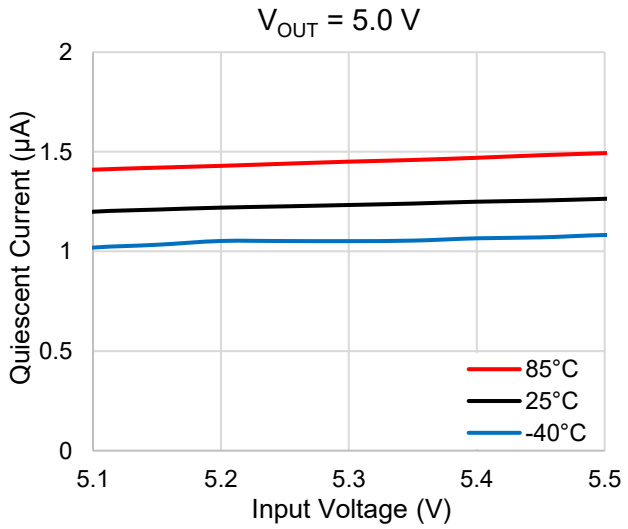
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13.4. Quiescent Current vs. Input Voltage

(I_{OUT} = 0 mA)



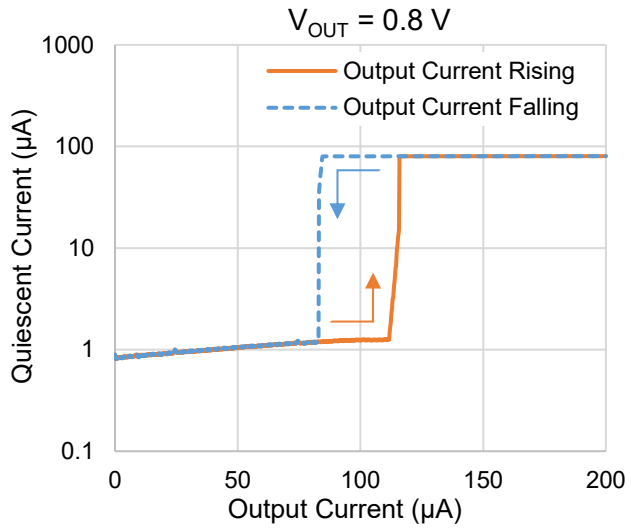


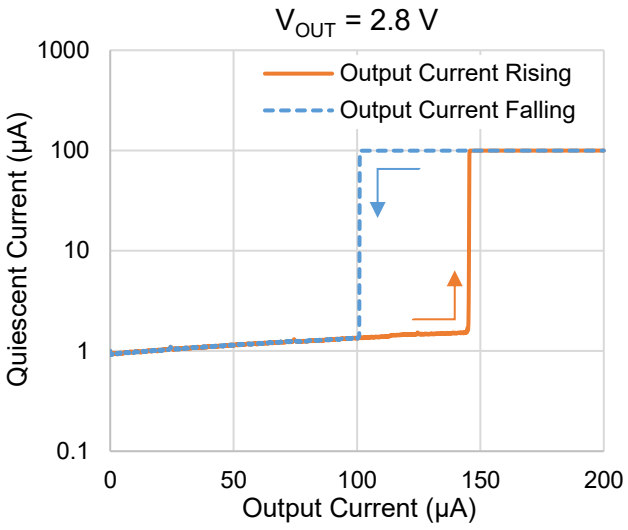


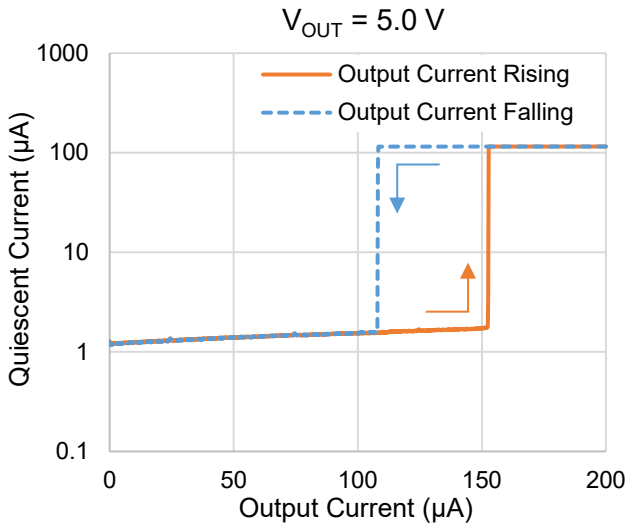
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

13.5. Quiescent Current vs. Output Current

(V_{IN} = 2.5 V (V_{OUT} = 0.8 V) or 3.8 V (V_{OUT} = 2.8 V) or 5.5 V (V_{OUT} = 5.0 V), I_{OUT} = 0 A ⇔ 200 μA, Ta = 25 °C)



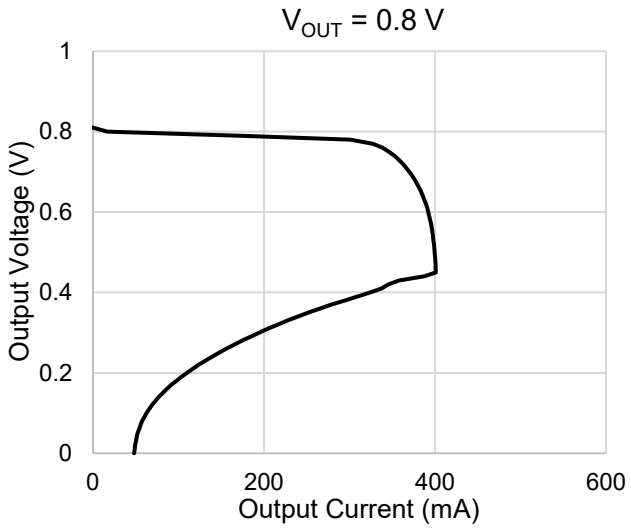


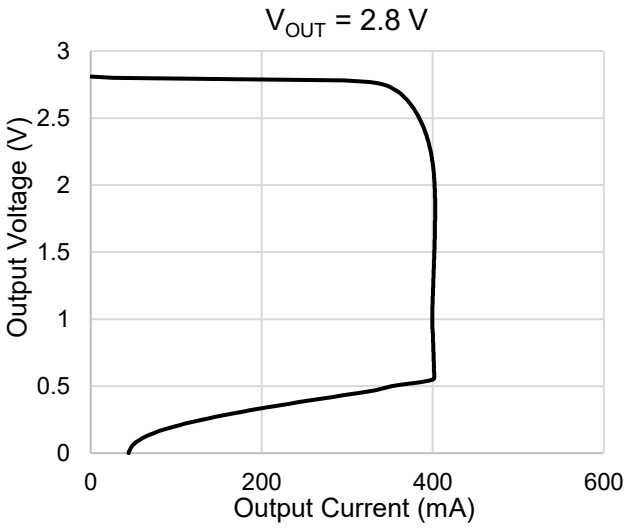


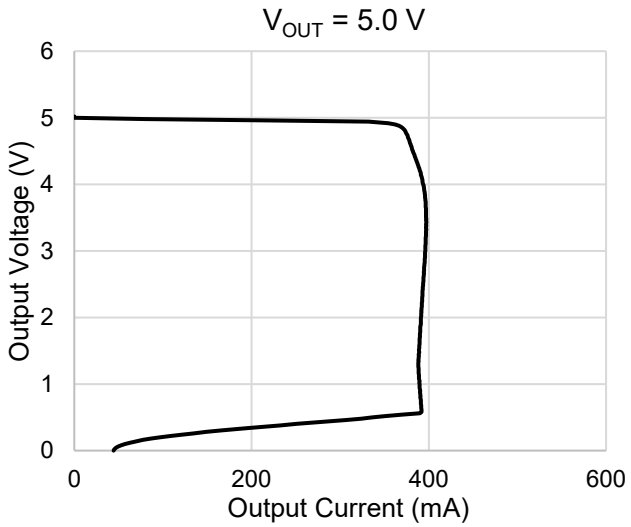
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

13.6. Output Current Limit

(V_{IN} = 2.5 V (V_{OUT} = 0.8 V) or 3.8 V (V_{OUT} = 2.8 V) or 5.5 V (V_{OUT} = 5.0 V), Ta = 25 °C)



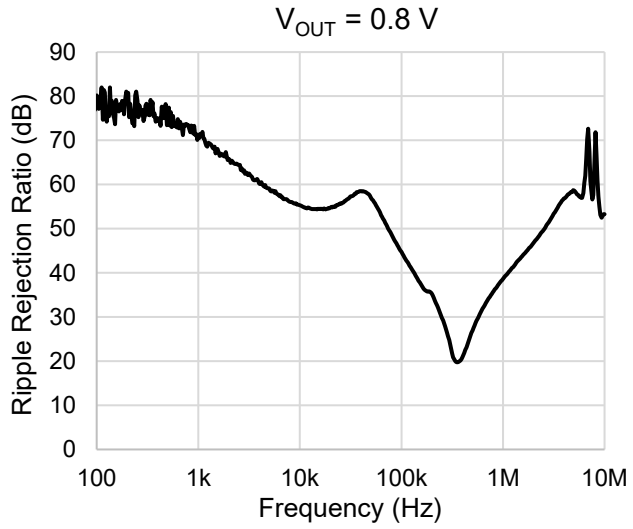


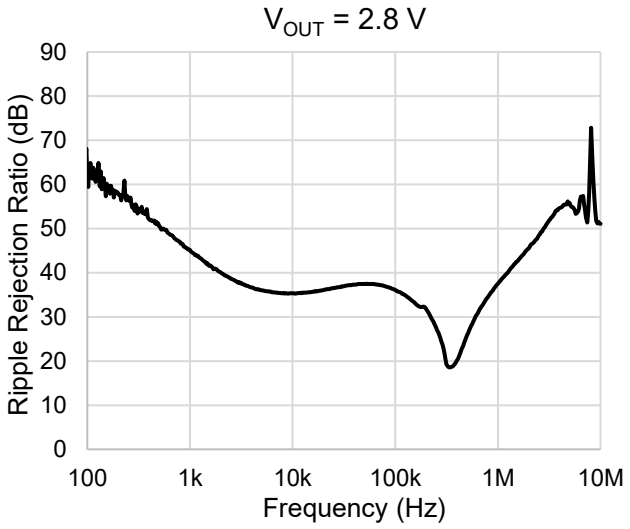


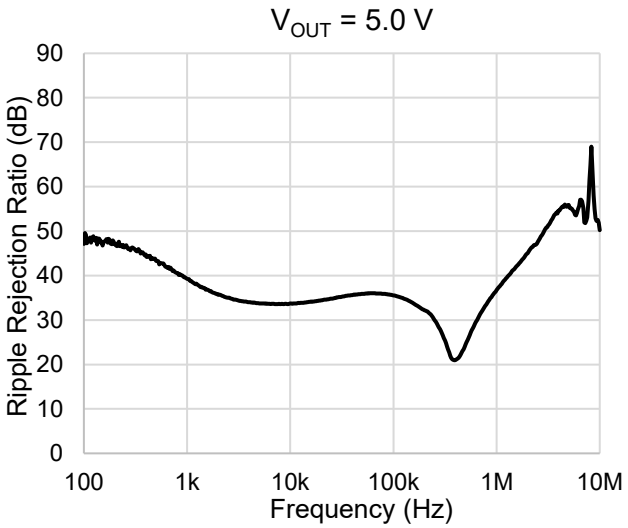
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

13.7. Ripple rejection Ratio vs. Frequency

(C_{IN} = none, C_{OUT} = 0.47 µF, V_{IN} = 2.5 V (V_{OUT} = 0.8 V) or 3.8 V (V_{OUT} = 2.8 V) or 5.5 V (V_{OUT} = 5.0 V), $V_{IN\ Ripple}$ = 200 mV_{p-p}, I_{OUT} = 10 mA, Ta = 25 °C)





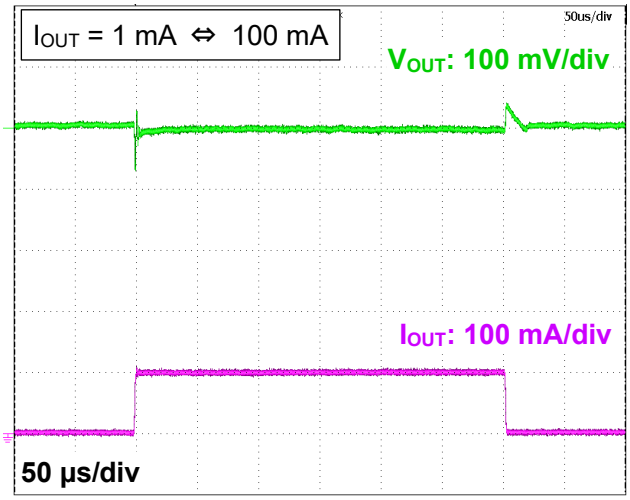


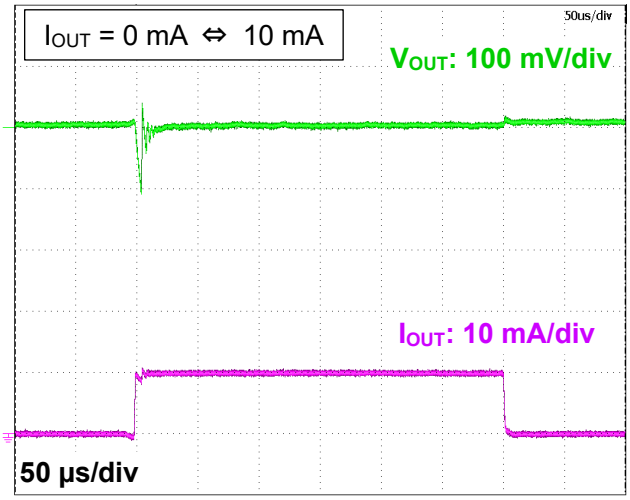
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

13.8. Load Transient Response

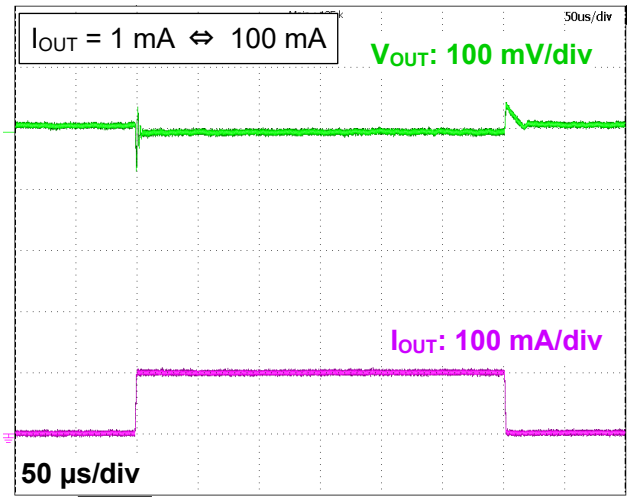
(C_{IN} = 0.47 µF, C_{OUT} = 0.47 µF, V_{IN} = 2.5 V (V_{OUT} = 0.8 V) or 3.8 V (V_{OUT} = 2.8 V) or 5.5 V (V_{OUT} = 5.0 V), t_r = 1.0 µs, t_f = 1.0 µs, Ta = 25 °C)

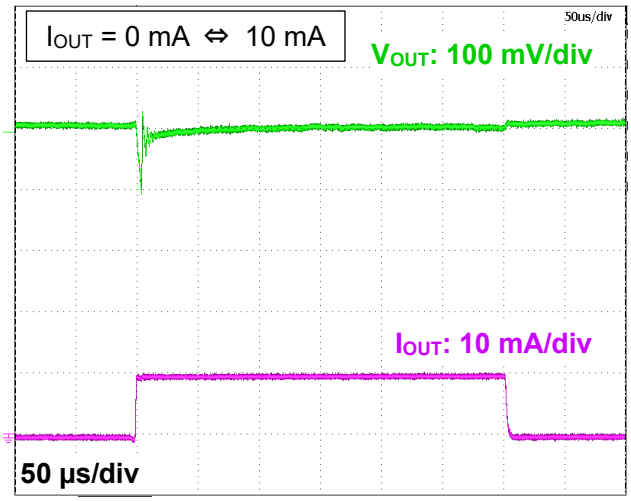
V_{OUT} = 0.8 V



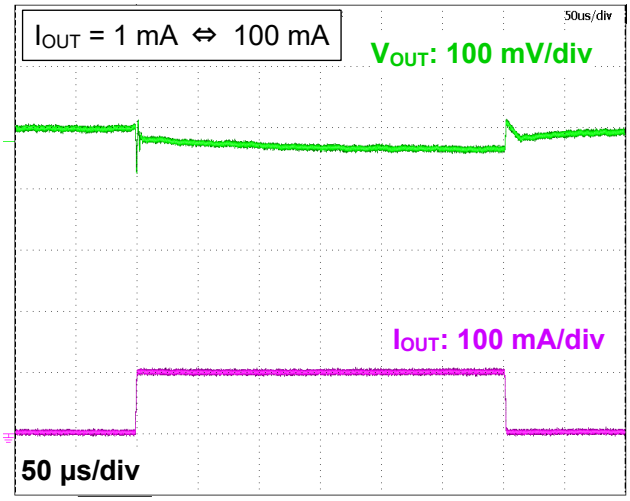


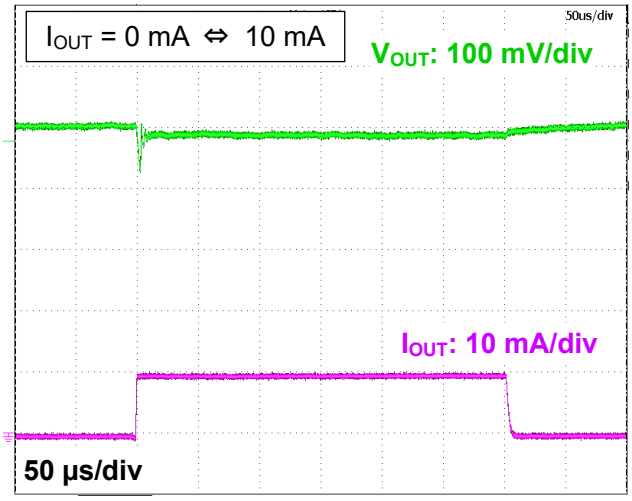
V_{OUT} = 2.8 V





V_{OUT} = 5.0 V





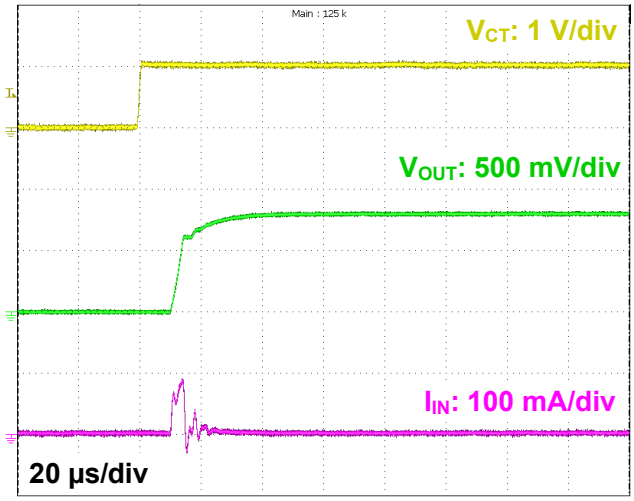
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

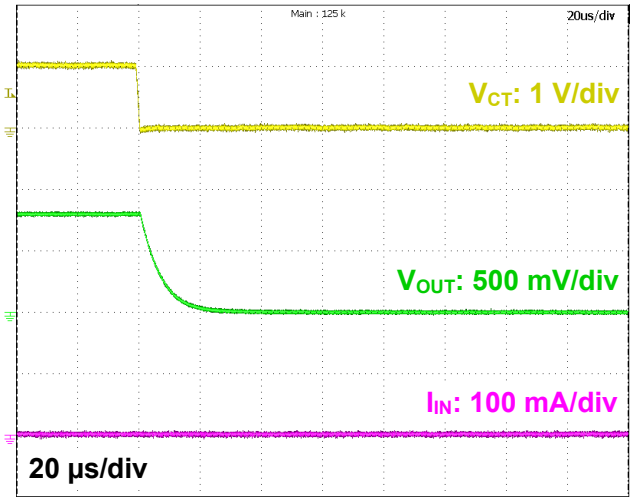
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13.9. t_{ON}/t_{OFF} Response

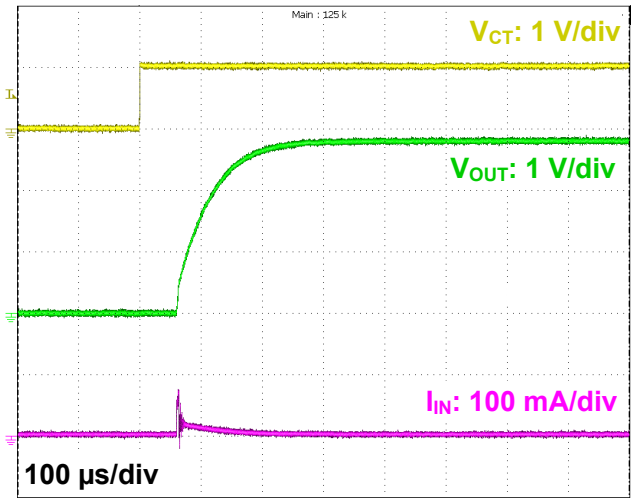
(C_{IN} = 0.47 µF, C_{OUT} = 0.47 µF, V_{IN} = 2.5 V (V_{OUT} = 0.8 V) or 3.8 V (V_{OUT} = 2.8 V) or 5.5 V (V_{OUT} = 5.0 V), I_{OUT} = 0 mA, V_{CT} = 0 V ⇔ 1.0 V, Ta = 25 °C)

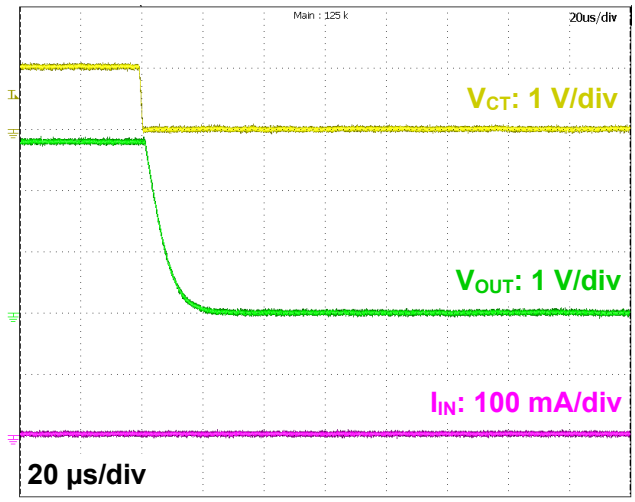
V_{OUT} = 0.8 V



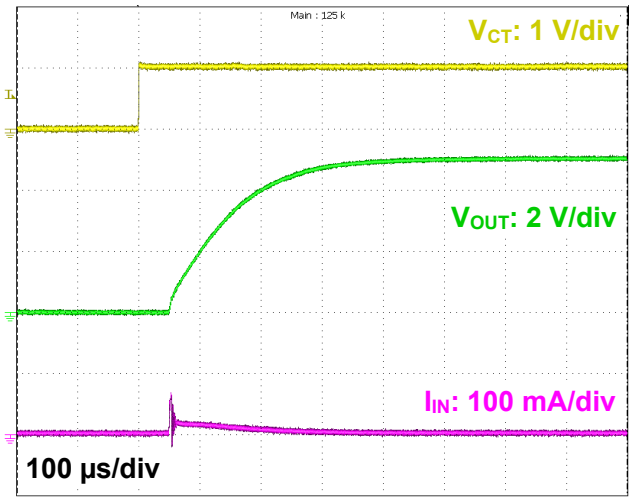


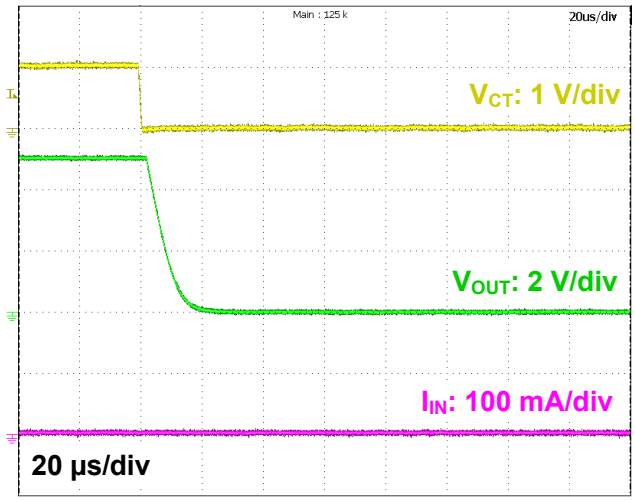
V_{OUT} = 2.8 V





V_{OUT} = 5.0 V





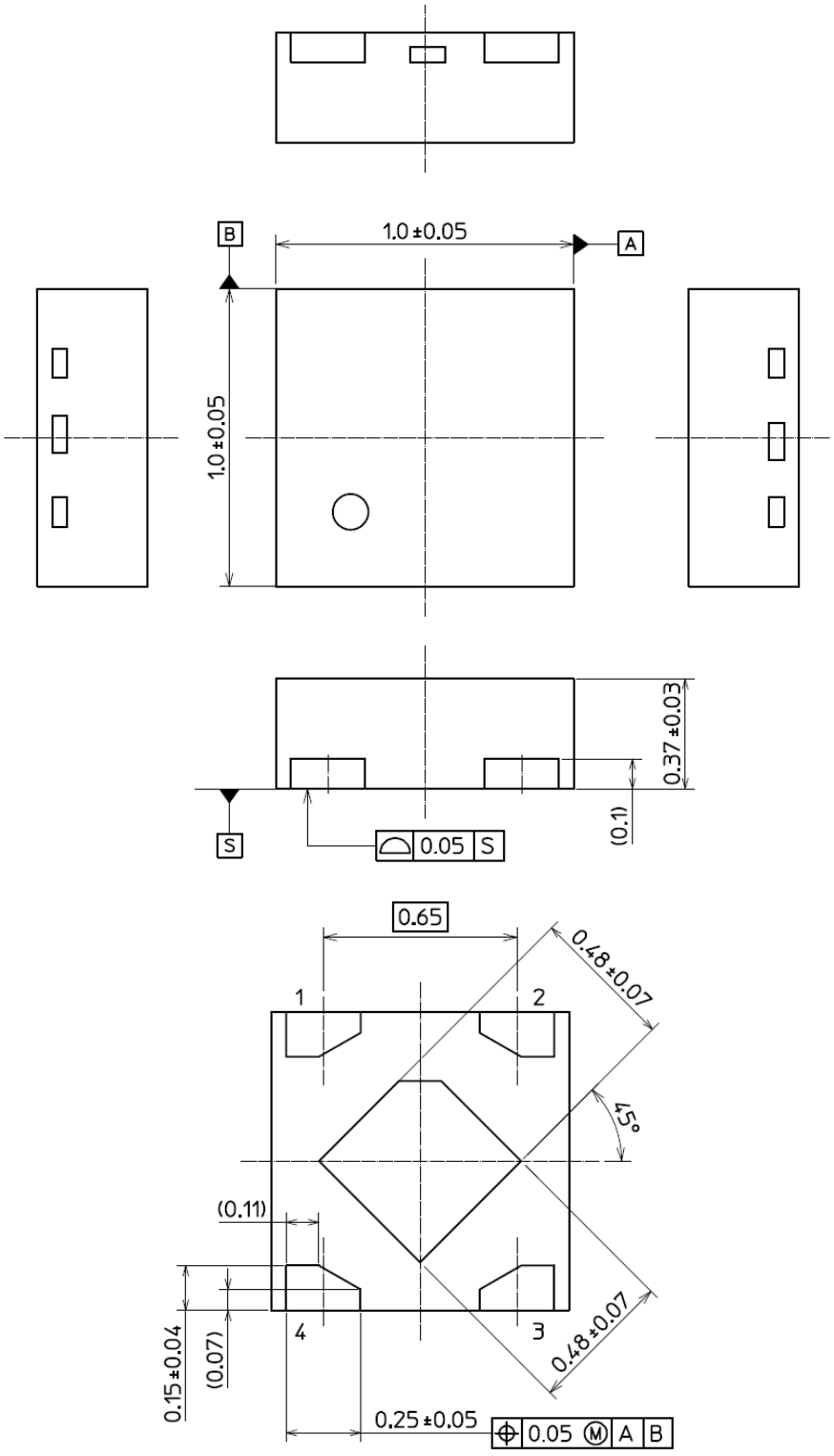
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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14. Package Information

DFN4D

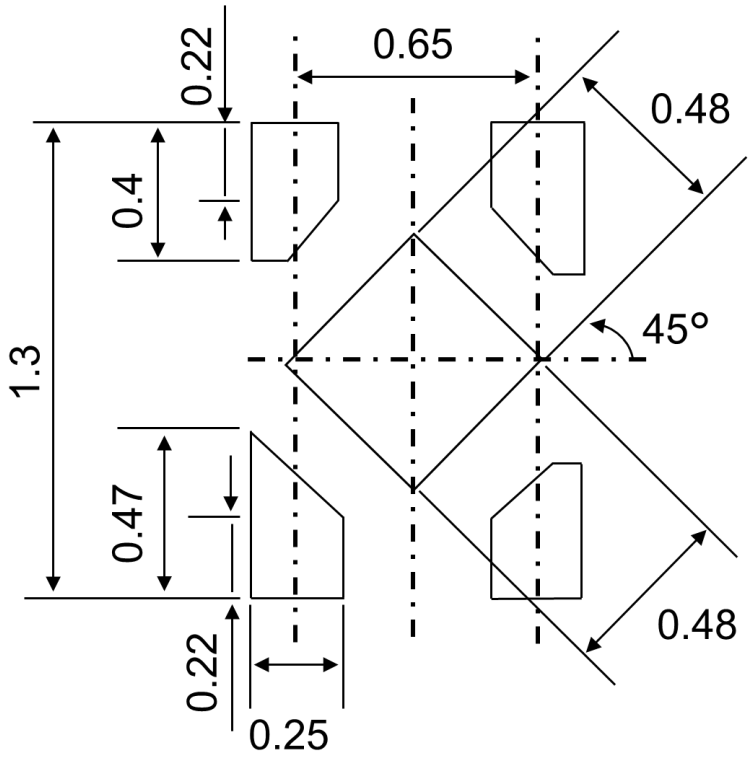
Unit: mm



Weight: 1.1 mg (typ.)

15. Land Pattern Dimensions (for reference only)

Unit: mm



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